TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

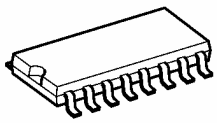
TC74VHC367F,TC74VHC367FN,TC74VHC367FT,TC74VHC367FK
TC74VHC368F,TC74VHC368FN,TC74VHC368FT,TC74VHC368FK

Hex Bus Buffer

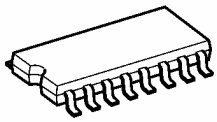
TC74VHC367F/FN/FT	Non-Inverted, 3-State Outputs
TC74VHC368F/FN/FT	Inverted, 3-State Outputs

Note: The JEDEC SOP (FN) is not available in Japan.

TC74VHC367F, TC74VHC368F

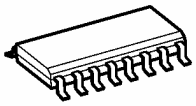


SOP16-P-300-1.27A



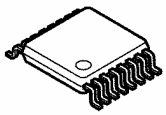
SOP16-P-300-1.27

TC74VHC367FN, TC74VHC368FN



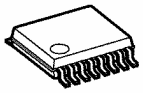
SOL16-P-150-1.27

TC74VHC367FT, TC74VHC368FT



TSSOP16-P-0044-0.65A

TC74VHC367FK, TC74VHC368FK



VSSOP16-P-0030-0.50

The TC74VHC367 and 368 are advanced high speed CMOS HEX BUS BUFFERs fabricated with silicon gate C^2MOS technology.

They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

They contain six buffers; four buffers are controlled by an enable input ($\overline{G}1$), and the other two buffers are controlled by another enable input ($\overline{G}2$). The outputs of each buffer group are enabled when $\overline{G}1$ and/or $\overline{G}2$ inputs are held low; if held high, these outputs are in a high impedance state.

The TC74VHC367 is a non-inverting output type, while the TC74VHC368 is an inverting output type.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

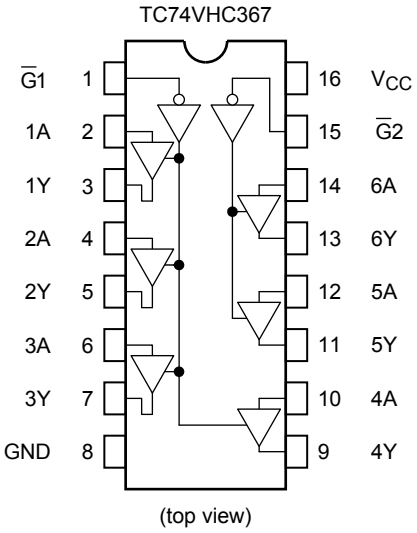
Features

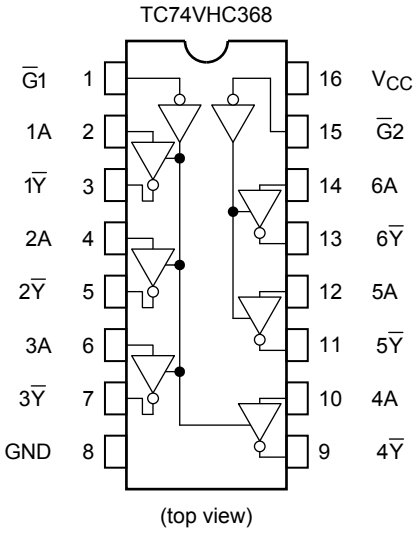
- High speed: t_{pd} = 3.8 ns (typ.) at V_{CC} = 5 V
- Low power dissipation: I_{CC} = 4 μA (max) at Ta = 25°C
- High noise immunity: $V_{NIH} = V_{NIL}$ = 28% V_{CC} (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: $V_{CC\ (opr)}$ = 2 V to 5.5 V
- Low noise: V_{OLP} = 0.8 V (max)
- Pin and function compatible with 74ALS367/368

Weight

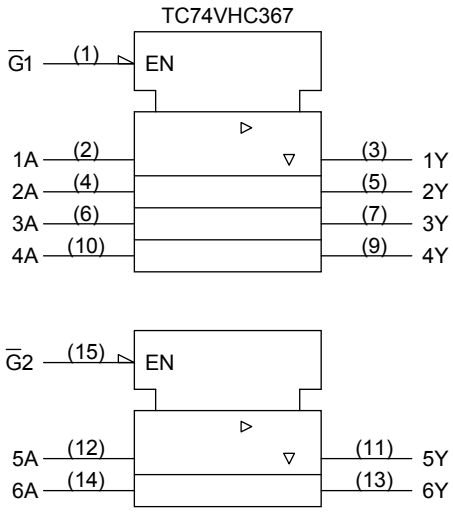
SOP16-P-300-1.27A	: 0.18 g (typ.)
SOP16-P-300-1.27	: 0.18 g (typ.)
SOL16-P-150-1.27	: 0.13 g (typ.)
TSSOP16-P-0044-0.65A	: 0.06 g (typ.)
VSSOP16-P-0030-0.50	: 0.02 g (typ.)

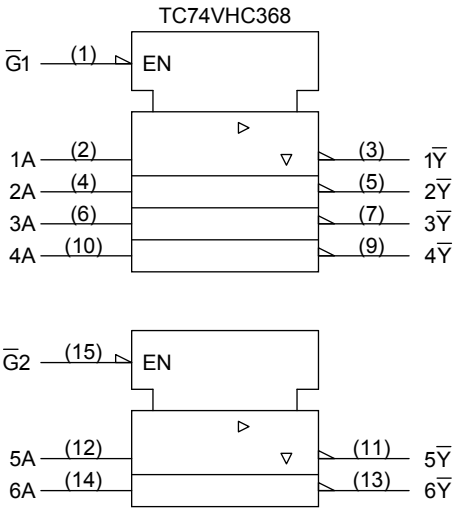
Pin Assignment





IEC Logic Symbol





Truth Table

Inputs		Outputs	
$\overline{G}$	A	Y (367)	$\overline{Y}$ (368)
L	L	L	H
L	H	H	L
H	X	Z	Z

X: Don’t care

Z: High impedance

Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	−0.5 to 7.0	V
DC input voltage	V_{IN}	−0.5 to 7.0	V
DC output voltage	V_{OUT}	−0.5 to V_{CC} + 0.5	V
Input diode current	I_{IK}	−20	mA
Output diode current	I_{OK}	±20	mA
DC output current	I_{OUT}	±25	mA
DC V_{CC}/ground current	I_{CC}	±50	mA
Power dissipation	P_D	180	mW
Storage temperature	T_{stg}	−65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Operating Range (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2.0 to 5.5	V
Input voltage	V_{IN}	0 to 5.5	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Operating temperature	T_{opr}	−40 to 85	°C
Input rise and fall time	dt/dv	0 to 100 (V_{CC} = 3.3 ± 0.3 V) 0 to 20 (V_{CC} = 5 ± 0.5 V)	ns/V

Note: The operating range must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		V_{CC} (V)	Ta = 25°C Min	Ta = 25°C Typ.	Ta = 25°C Max	Ta = −40 to 85°C Min	Ta = −40 to 85°C Max	Unit
High-level input voltage	V_{IH}	—		2.0	1.50	—	—	1.50	—	V
				3.0 to 5.5	V_{CC} × 0.7	—	—	V_{CC} × 0.7	—	
Low-level input voltage	V_{IL}	—		2.0	—	—	0.50	—	0.50	V
				3.0 to 5.5	—	—	V_{CC} × 0.3	—	V_{CC} × 0.3	
High-level output voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	I_{OH} = −50 μA	2.0	1.9	2.0	—	1.9	—	V
				3.0	2.9	3.0	—	2.9	—	
				4.5	4.4	4.5	—	4.4	—	
			I_{OH} = −4 mA	3.0	2.58	—	—	2.48	—	
			I_{OH} = −8 mA	4.5	3.94	—	—	3.80	—	
Low-level output voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	I_{OL} = 50 μA	2.0	—	0.0	0.1	—	0.1	V
				3.0	—	0.0	0.1	—	0.1	
				4.5	—	0.0	0.1	—	0.1	
			I_{OL} = 4 mA	3.0	—	—	0.36	—	0.44	
			I_{OL} = 8 mA	4.5	—	—	0.36	—	0.44	
3-state output off-state current	I_{OZ}	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND		5.5	—	—	±0.25	—	±2.50	μA
Input leakage current	I_{IN}	V_{IN} = 5.5 V or GND		0 to 5.5	—	—	±0.1	—	±1.0	μA
Quiescent supply current	I_{CC}	V_{IN} = V_{CC} or GND		5.5	—	—	4.0	—	40.0	μA

AC Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = −40 to 85°C		Unit
			V_{CC} (V)	C_L (pF)	Min	Typ.	Max	Min	Max	
Propagation delay time (TC74VHC367)	t_{pLH} t_{pHL}	—	3.3 ± 0.3	15	—	5.9	8.3	1.0	10.0	ns
				50	—	8.4	11.8	1.0	13.5	
			5.0 ± 0.5	15	—	4.1	5.9	1.0	7.0	
				50	—	5.6	7.9	1.0	9.0	
Propagation delay time (TC74VHC368)	t_{pLH} t_{pHL}	—	3.3 ± 0.3	15	—	5.3	7.5	1.0	9.0	ns
				50	—	7.8	11.0	1.0	12.5	
			5.0 ± 0.5	15	—	3.8	5.5	1.0	6.5	
				50	—	5.3	7.5	1.0	8.5	
3-state output enable time	t_{pZL} t_{pZH}	R_L = 1 kΩ	3.3 ± 0.3	15	—	6.8	10.5	1.0	12.5	ns
				50	—	9.3	14.0	1.0	16.0	
			5.0 ± 0.5	15	—	4.8	7.2	1.0	8.5	
				50	—	6.3	9.2	1.0	10.5	
3-state output disable time	t_{pLZ} t_{pHZ}	R_L = 1 kΩ	3.3 ± 0.3	50	—	9.9	13.6	1.0	15.5	ns
			5.0 ± 0.5	50	—	6.3	9.2	1.0	10.5	
Output to output skew	t_{osLH} t_{osHL}	(Note 1)	3.3 ± 0.3	50	—	—	1.5	—	1.5	ns
			5.0 ± 0.5	50	—	—	1.0	—	1.0	
Input capacitance	C_{IN}	—			—	4	10	—	10	pF
Output capacitance	C_{OUT}	—			—	6	—	—	—	pF
Power dissipation capacitance	C_{PD}	(Note 2)			—	19	—	—	—	pF

Note 1: Parameter guaranteed by design.

$t_{osLH} = |t_{pLHm} - t_{pLHn}|$, $t_{osHL} = |t_{pHLm} - t_{pHLn}|$

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

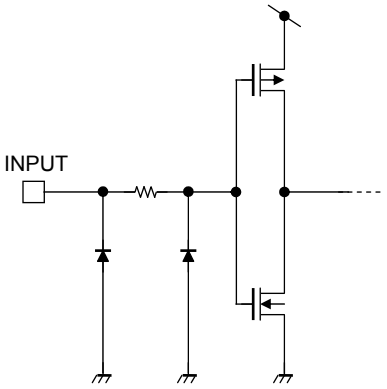
Average operating current can be obtained by the equation:

$I_{CC\ (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/6$ (per bit)

Noise Characteristics (input: $t_r = t_f = 3$ ns)

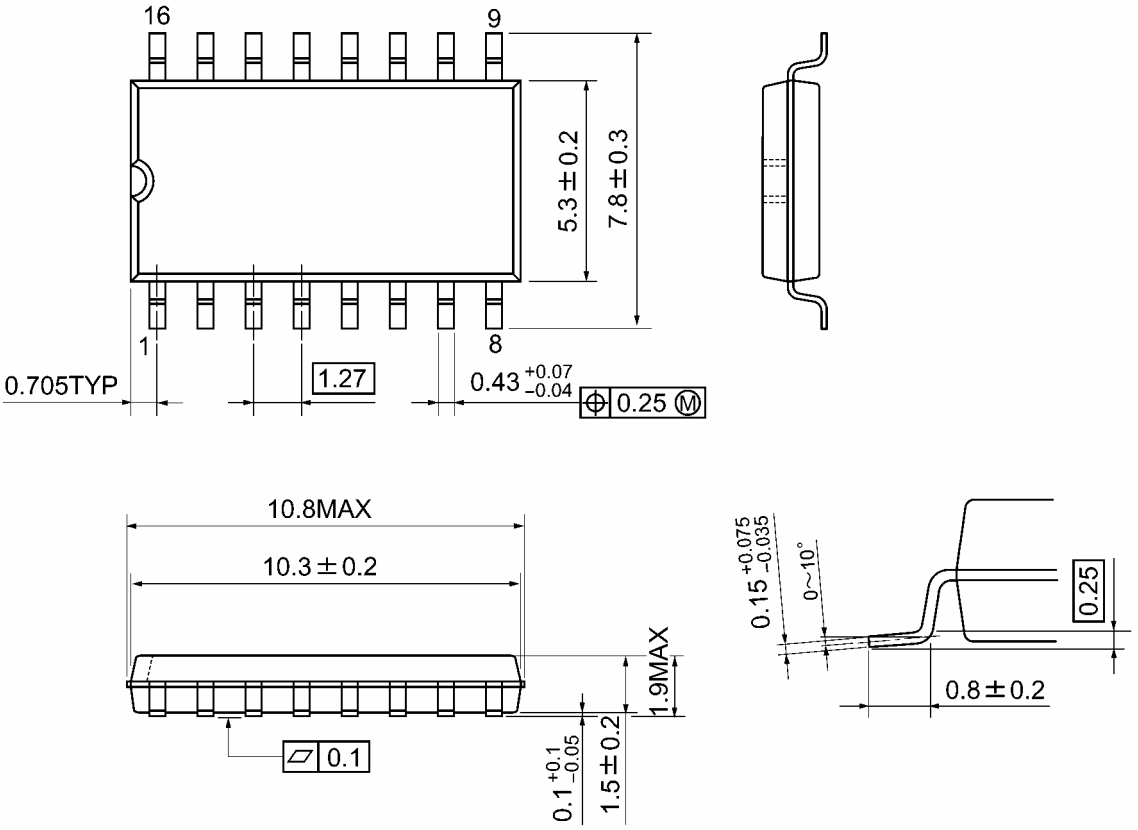
Characteristics	Symbol	Test Condition	Ta = 25°C			Unit
			V_{CC} (V)	Typ.	Max	
Quiet output maximum dynamic V_{OL}	V_{OLP}	C_L = 50 pF	5.0	0.4	0.8	V
Quiet output minimum dynamic V_{OL}	V_{OLV}	C_L = 50 pF	5.0	−0.4	−0.8	V
Minimum high level dynamic input voltage	V_{IHD}	C_L = 50 pF	5.0	—	3.5	V
Maximum low level dynamic input voltage	V_{ILD}	C_L = 50 pF	5.0	—	1.5	V

Input Equivalent Circuit



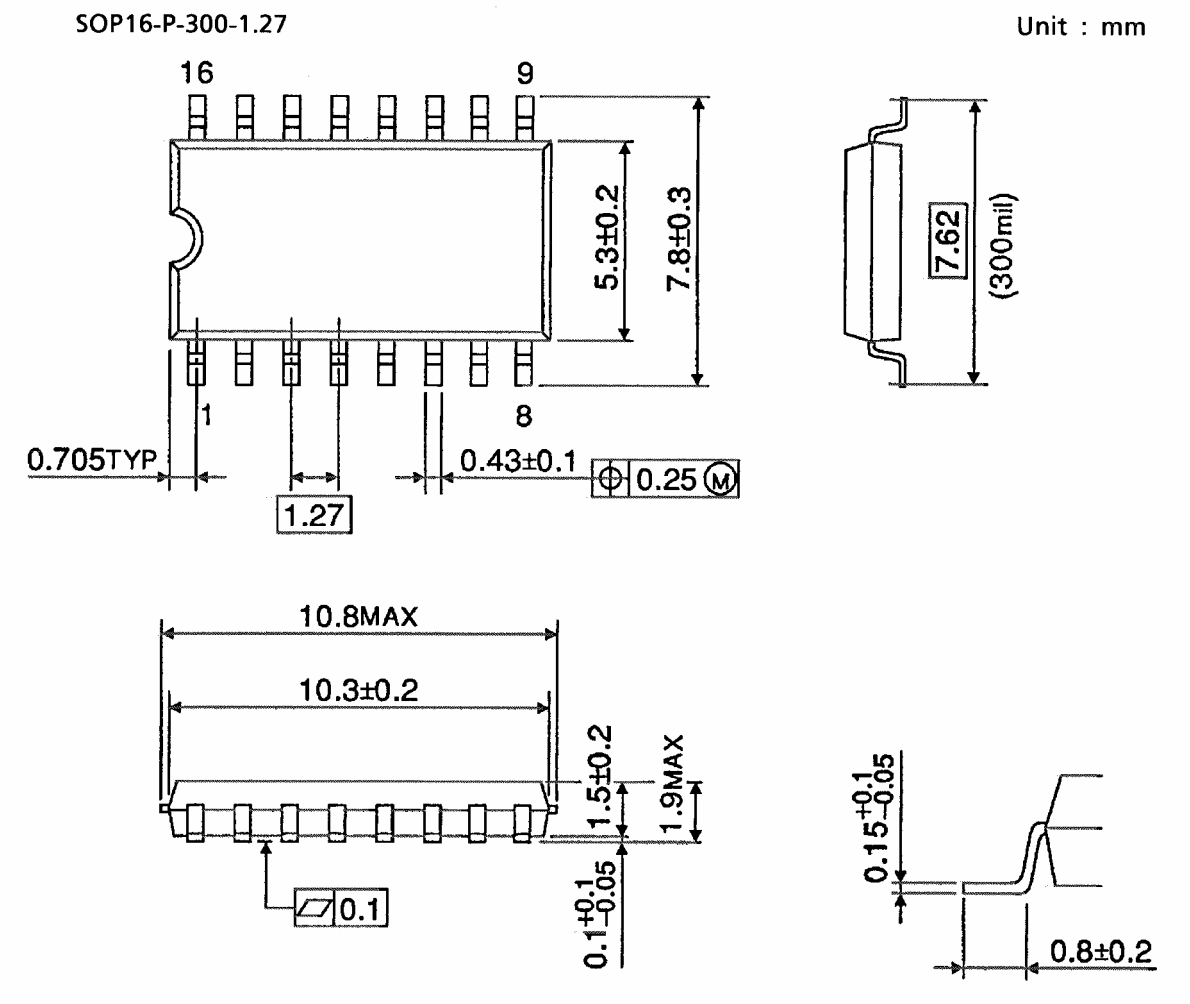
Package Dimensions

SOP16-P-300-1.27A Unit: mm



Weight: 0.18 g (typ.)

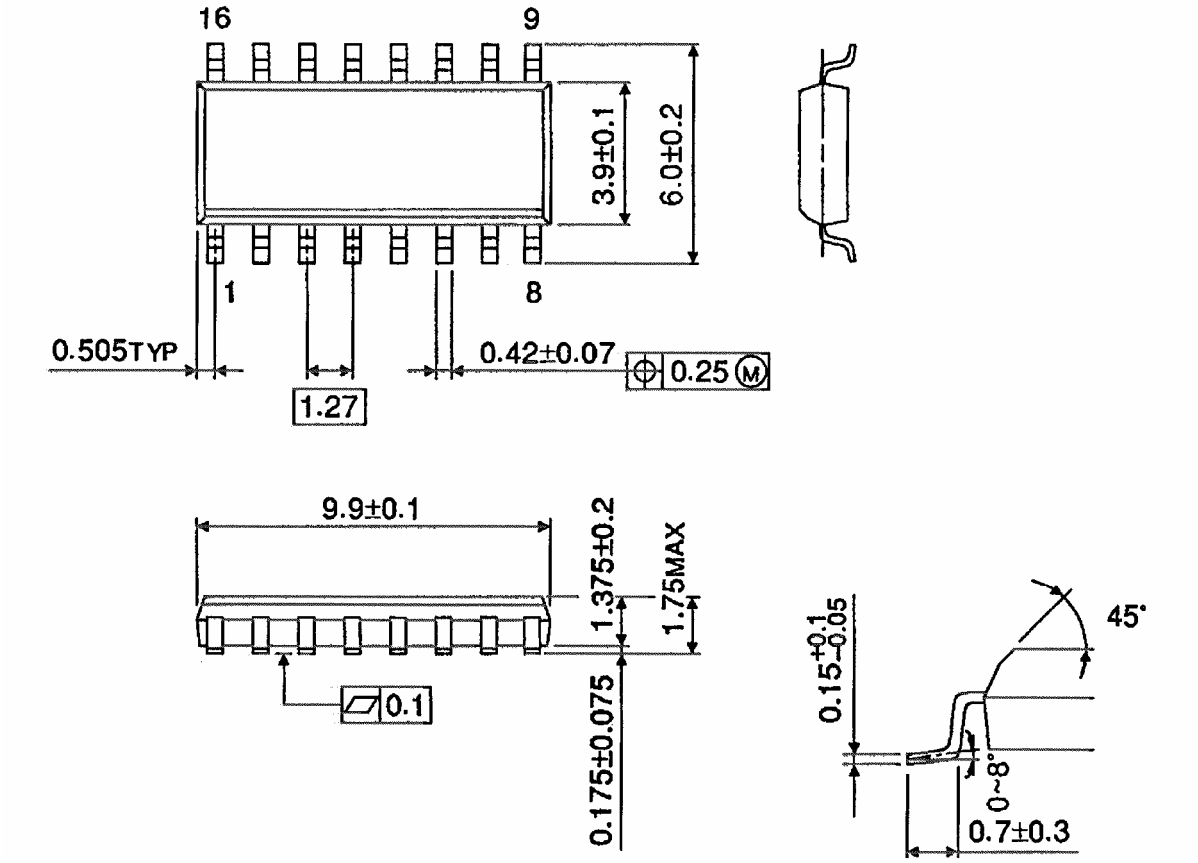
Package Dimensions



Weight: 0.18 g (typ.)

Package Dimensions (Note)

SOL16-P-150-1.27 Unit : mm

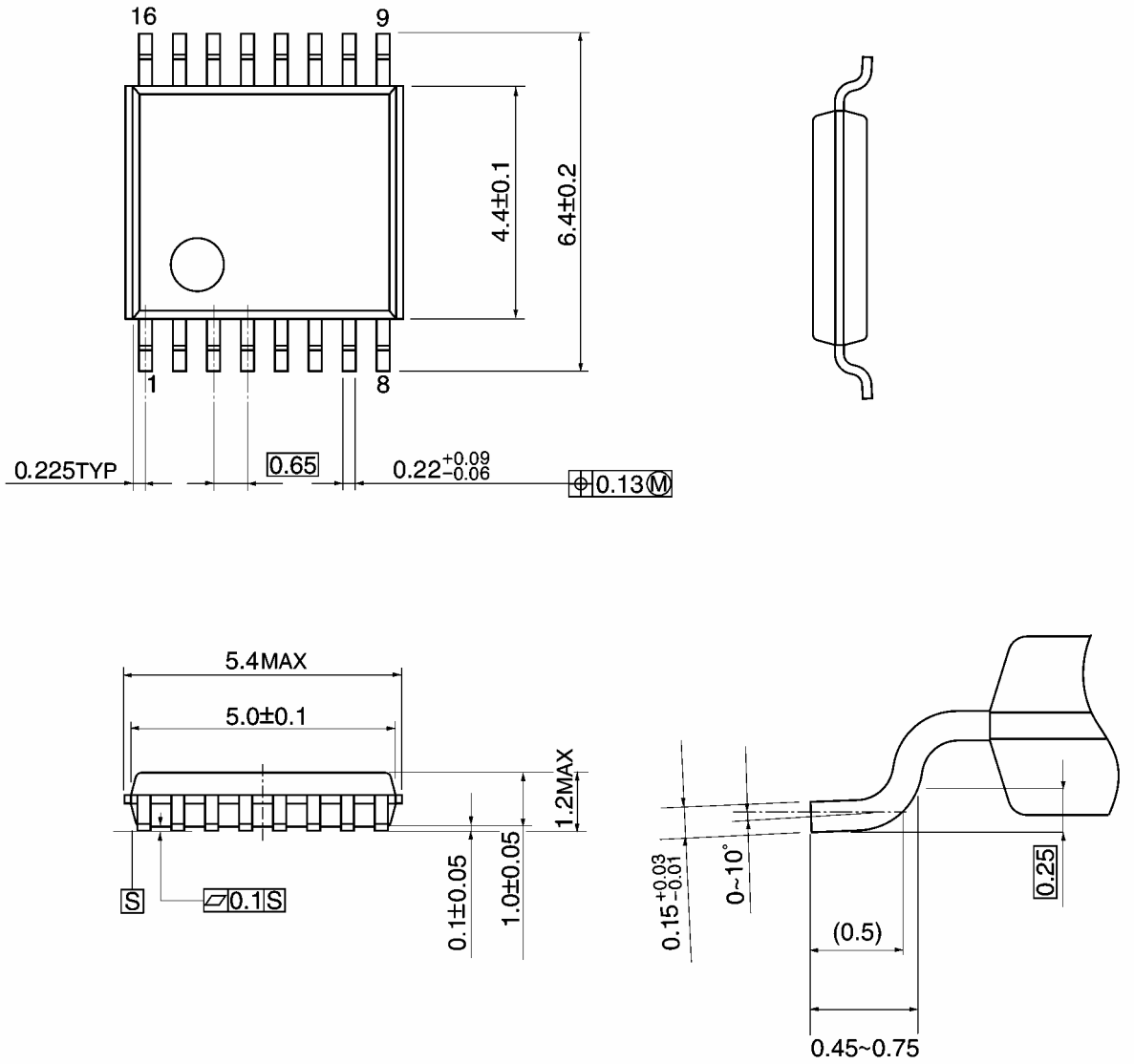


Note: This package is not available in Japan.

Weight: 0.13 g (typ.)

Package Dimensions

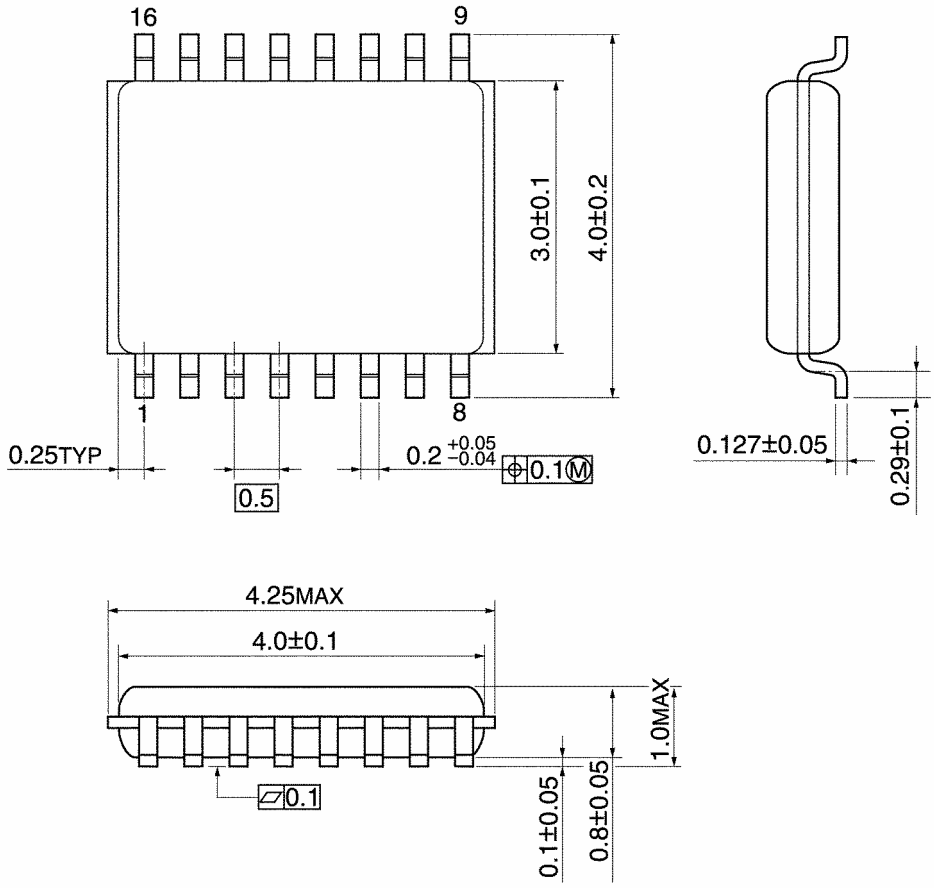
TSSOP16-P-0044-0.65A Unit: mm



Weight: 0.06 g (typ.)

Package Dimensions

VSSOP16-P-0030-0.50 Unit: mm



Weight: 0.02 g (typ.)

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